### MBR220F~MBR2200F

SCHOTTKY BARRIER RECTIFIER

REVERSE VOLTAGE 20V TO 200V FORWARD CURRENT 2.0A

# **DESCRIPTION**

The MBR220F~MBR2200F are available in SOD-123FL package

# **FEATURES**

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Available in SOD-123FL package

### ORDERING INFORMATION

Package Type	Part Number				
SOD-123FL	MBR220F				
	MBR240F				
	MBR260F				
	MBR280F				
	MBR2100F				
	MBR2120F				
	MBR2150F				
	MBR2200F				
Note	SPQ: 3,000pcs/Reel				
AiT provides all RoHS Compliant Products					

### PIN DESCRIPTION



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# ABSOLUTE MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20%

Parameter Parameter		Symbol	MBR 220F	MBR 240F	MBR 260F	MBR 280F	MBR 2100F	MBR 2120F	MBR 2150F	MBR 2200F	Unit
Maximum Repetitive Peak		.,	00	40	00	00	400	400	450	000	
Reverse Voltage		V <sub>RRM</sub>	20	40	60	80	100	120	150	200	V
Maximum RMS Vol	tage	V <sub>RMS</sub>	14	28	42	56	80	100	105	140	٧
Maximum DC Black	king Voltage	V <sub>DC</sub>	20	40	60	80	100	120	150	200	V
Maximum Average	Maximum Average Forward		2.0								А
Rectified Current	Rectified Current										
Peak Forward Surge Current,											
8.3ms Single Half Sine-wave			40								A
Superimposed on Rated Load		I <sub>FSM</sub>	40								
(JEDEC method)											
Max Instantaneous Forward		VF	0.55		0.70		0.85		0.95		V
Voltage at 2A		VF									
Maximum DC											
Reverse Current	T <sub>A</sub> =25°C	1-	0.5 10					0.3			mA
at Rated DC	T <sub>A</sub> =100°C	I <sub>R</sub>					5				
Reverse Voltage											
Typical Junction Capacitance <sup>NOTE1</sup>			220 80						pF		
Operating Junction Temperature		TJ	-55~+125							°C	
Range		I J									
Storage Temperatu	T <sub>STG</sub>	-55~+150								Ô	

NOTE1: Measured at 1MHz and applied reverse voltage of 4V D.C.

## TYPICAL CHARACTERISTICS

Figure 1. Forward Current Derating Curve

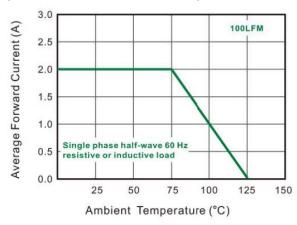


Figure 3. Typical Forward Characteristic

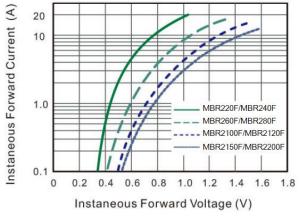


Figure 5. Maximum Non-Repetitive Peak

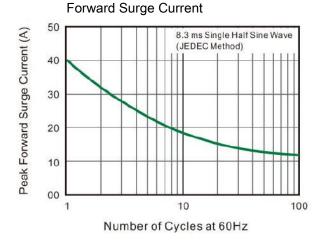


Figure 2. Typical Reverse Characteristics

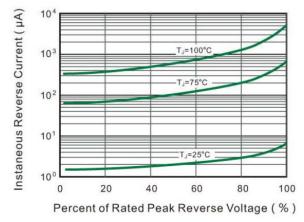
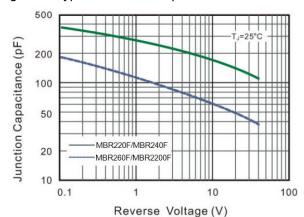
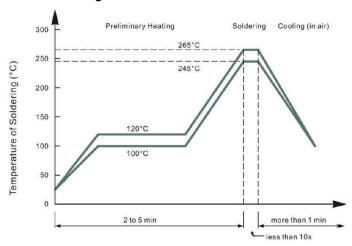


Figure 4. Typical Junction Capacitance

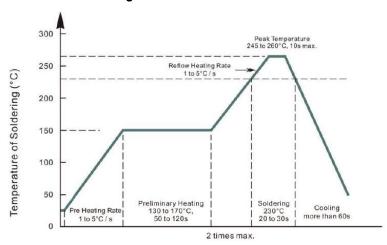


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### Recommended condition of flow soldering



#### Recommended condition of reflow soldering



Recommended peak temperature is over 245°C. If peak temperature is below 245°C, you may adjust the following parameters; time length of peak temperature (longer), time length of soldering (longer), thickness of solder paste (thicker)

#### Condition of hand soldering

Temperature: 320°C

Time: 3s max. Times: one time

#### Remark

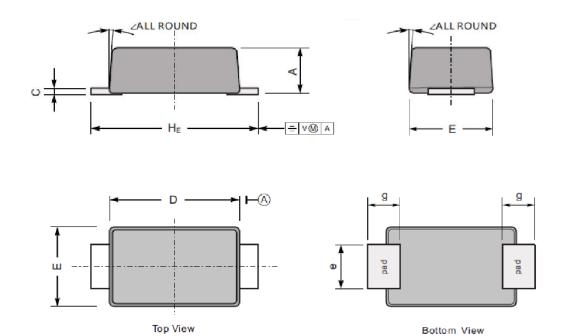
Lead free solder paste (96.5Sn/3.0Ag/0.5Cu)

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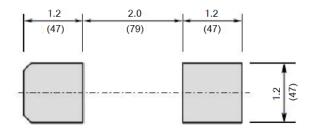
# PACKAGE INFORMATION

Dimension in SOD-123FL (Unit: mm)

Plastic Surface mounted package; 2 leads



The recommended mounting pad size



Unit: mm (mil)

UN	UNIT		С	D	Е	е	g	HE	∠	
mm	Max	1.1	0.20	2.9	1.9	1.1	0.9	3.8		
	Min	0.9	0.12	2.6	1.7	0.8	0.7	3.5	70	
mil	Max	43	7.9	114	75	43	35	150	7°	
	Min	35	4.7	102	67	31	28	138		

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